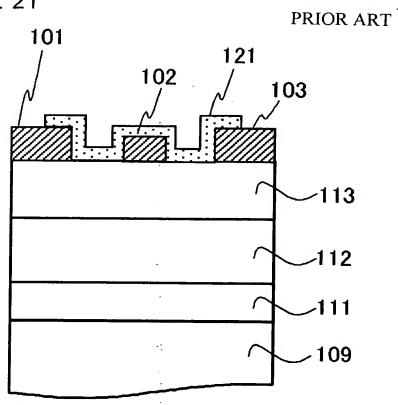


20 / 38

Title: FIELD-EFFECT TRANSISTOR HAVING GROUP III NITRIDE ELECTRODE STRUCTURE Inventor(s): Yasuhiro OKAMOTO et al. Appl. No.: 10/538,739

FIG. 21



21 / 38

